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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Bong-Cheol Kim
Serial No. : 10/089,479 Examiner: To Be Assigned
Filed : March 28, 2002 Group Art Unit: 2812
For : APPARATUS AND METHOD FOR FORMING SINGLE CRYSTALLINE NITRIDE SUBSTRATE USING HYDRIDE VAPOR PHASE EPITAXY AND LASER BEAM

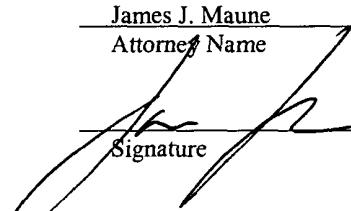
INFORMATION DISCLOSURE STATEMENT

I hereby certify that this paper is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231

September 3, 2002
Date of Deposit

James J. Maune
Attorney Name

26,946
PTO Registration No.


Signature

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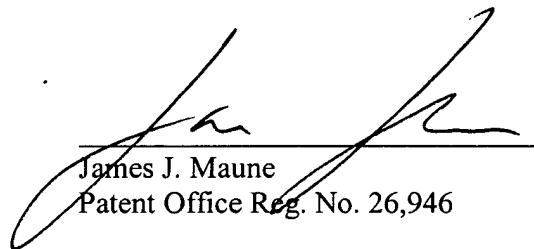
Commissioner for Patents
Washington, D.C. 20231

Sir:

Pursuant to the provisions of 37 C.F.R. §§ 1.97 and 1.98, Applicant respectfully requests that the references relating to the above-mentioned application listed on attached PTO Form 1449, be made of record in the U.S. Patent and Trademark office. Copies of the referenced citations are enclosed.

No fee is believed to be required in connection with this communication. However, if a fee is required, the Commissioner is hereby authorized to charge the payment of any fees to Deposit Account No. 02-4377.

Respectfully submitted,



James J. Maune
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Enclosures